Electrical Characteristics/Operating Characteristics at $Ta = 25^{\circ}C$, $V_{CC} = 5.0V$, Measured with US3ch unless otherwise specified

Parameter	Symbol	Conditions	Ratings			Unit
Falameter		Conditions		typ	max	Unit
Current drain 1	ICC1	No signal, pin 6 high	28	41	53	mA
Current drain 2	ICC2	No signal, pin 6 low	15	22	29	m/
Regulator voltage	Vreg	No signal	3.7	3.9	4.1	V
Antenna driver voltage	Vanton	Pin 6 high, 220Ω load	3.2	3.5	3.8	V
Negative Resistance (pin7)	-R	Cl≤100	1.2	2.2		kΩ
RF type						
Video carrier frequency accuracy	Fp	Fp (US3ch): 61.25MHz	05		0.5	
		X'tal accuracy 30ppm	-25		25	kH
Video carrier frequency stability	Fpt	X'tal accuracy 30ppm	-25		25	kH
		Ta = 4°C to 38°C	20		20	
Video carrier output US	Pus	No signal (Note 1)	85.5	87.5	89.5	dB
Audio carrier output ratio	P/S	S: fp + 4.5MHz	14.5	16	17.5	dE
Audio 2 nd harmonic distortion	P/S2	S2: fp + 2 × 4.5MHz	50	65		dE
Audio 3 rd harmonic distortion	P/S3	S3: fp + 3 × 4.5MHz	45	55		dE
Chroma beat	P/CB	Vin = 3.58MHz, 0.6Vp-p	6F	74		٩Ľ
		CB: fp + 920kHz	65	74		dE
Video harmonic distortion	P/V2	Vin = 1MHz, 1Vp-p	45	72		dE
		V2: fp + 2MHz	10	12		
Video type			1	1	1	· · · · · ·
Video modulation	Мр	Vin = Stair step, 1Vp-p	75	80	85	%
White clip level	W _{CL}	Vin = Stair step, 1.5Vp-p	90	95	99	%
Differential gain	D _G	Vin = 10-Stair step, 1Vp-p	-5		5	%
		(Note 2)	-5		5	/0
Differential phase	DP	Vin = 10-Stair step, 1Vp-p	-5		5	°C
		(Note 2)				
Video signal frequency response	R _{fv}	Vin = CW, 1Vp-p	-1.1	-0.4	0.3	dE
Video S/N	Man	0.75 MHz to 3.75MHz Vin = 50%				
VIDEO 3/IN	V _{S/N}	4.2MHz LPF ON		50		dE
Audio type						<u> </u>
Audio carrier frequency accuracy	Fs	X'tal accuracy 30ppm	-5		5	kH
Audio modulation	Ms	Ain = 1kHz, 1Vp-p				
		(Note 3)	90	100	110	%
Maximum audio modulation	Msmx	THD < 3%	400			%
Audio distortion	THD	Ain = 1 kHz, 1Vp-p		0.4	2	%
Audio S/N	A _{S/N}	Ain = 1 kHz, 1Vp-p	45	50		
		Vin = Color bar, 1Vp-p	45	50		dE

Note 1: 9.5dB added to the RFOUT value measured with a spectrum analyzer of the input impedance of 50Ω .

Note 2: Difference between 1 stair step and 8 stair step of 10 stair step.

Note 3: $100\% = \pm 25$ kHz modulation.

Package Dimensions

unit : mm 3178B



Block Diagram



OMB05017

Pin equivalent circuit

	1			
Pin No.	Symbol	Voltage	Circuit	Remarks
1	P/S ADJ	2.7		Capacitor and additionally a Resistor may inserted between the circuit and GND attenuate the audio inter-carrier level.
2	AUDIO	0	2 100kΩ 7/7 7/7 7/7	FM audio Input.
3	FM LPF	2.2		Control pin of output FM oscilator for the PLL phase detector charge pump.
4	GND	0		
5	VIDEO IN	2.6		Video Input Clamped with sink chip.
6	CARR OFF	-		Hi:14pin Hi RF Operating Lo:14pin Lo RF Stop

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Pin No.	Symbol	Voltage	Circuit	Remarks	
7	IN XTAL	3.5	5PF 100Ω 500Ω 1 - W - T - T - T - T - T - T - T - T - T	4MHz oscillator inserted between the circuit and GND. External input of the 4MHz signal possible. Insertion of about 270kΩ resistor between the circuit and GND ensurescompatibility with 3.58MHz of VTR chroma sub-carrier. Insertion of about 270kΩ resistor between the circuit and V_{CC} ensurescompatibility with 27MHz of D-STB reference.	
8	СН	1.7	$33k\Omega$ (8) $17k\Omega$ (7)	CH selector pin US3: 4.2V or more US4: 2.7V to 3.8V	
9	PLL GND	0		PLL type GND	
10	RF GND	0		RF type GND	
11	V _{CC} 2	5.0		RF VCO type V _{CC}	
12	RF LPF	2.6	$\begin{array}{c} & & & \\ & & & & \\ & & & \\ & & & & \\ & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & &$	Control pin of output RF oscillator for the PLL phase detector charge pump.	

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Pin No.	Symbol	Voltage	Circuit	Remarks	
13	V _{CC} 1	5.0		V _{CC}	
14	ANT	3.5		Antenna SW driver pin.	
	DRV		50kΩ 1kΩ 1kΩ 1kΩ 100kΩ 100kΩ 100kΩ	15mA drive.	
15	RF OUT	3.0	15 1.5Ω	RF mixed signal output.	
16	REG	3.9		Regulator output.	

Test Circuit



Sample Application Circuit 1 (USch) for VCR







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